

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LB1973M — Two-channel H-Bridge Driver

Overview

The LB1973M is a two-channel H-bridge driver that supports for low saturation draive operation. It is optimal for H-bridge drive of stepping motors (AF and zoom) in portable equipment such as camera cell phones.

Features

- Two-channel H-bridge driver
- The range of the operation voltage is wide.(1.8V to 7.5V)
- Small package : MFP10S(225mil)
- Built-in thermal protection

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	V _{CC} max -0.3 to +8.0		V
Output voltage	V _{OUT} max		-0.3 to $V_{CC}+V_{SF}$	V
Input voltage	V _{IN} max	CONT, IN	-0.3 to +8.0	V
Ground pin source current	IGND	Per channel	1000	mA
Allowable power dissipation	Pd max1	For Unit	350	mW
	Pd max2	Mounted on a circuit board.*	870	mW
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

* Mounted on a Specified board : 114.3mm×76.1mm×1.6mm, glass epoxy

Allowable Operating Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		1.8 to 7.5	V
High-level input voltage	VIH		1.3 to 7.5	V
Low-level input voltage	V _{IL}		-0.3 to +0.5	V

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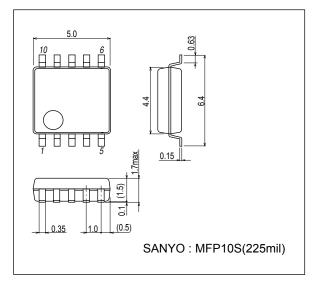
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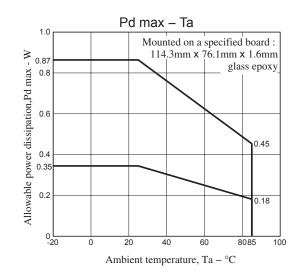
Electrical Characteristics at Ta = 25° C, V_{CC} = 1.9V

Decemeter	Symbol	Conditions	Ratings			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Source current	I _{CCO} 1	V _{CC} = 1.9V,IN1 to IN4 = 0V		0.01	1	μA
	I _{CCO2}	V _{CC} = 3V,IN1 to IN4 = 0V		0.01	1	μA
	I _{CC} 1	IN1 = 1.9V,IN2 to IN4 = 0V		18	25	mA
	I _{CC} 2	IN1 = 3V,IN2 to IN4 = 0V,V _{CC} = 3V		19	26	mA
Output saturation voltage1 (single connection)	V _{OUT} 11	$I_{OUT} = 270$ mA,V _{CC} = 1.9V to 3.6V,V _{OUT} = Upper Tr and Under Tr IN1 = 1.3V,IN2 to IN4 = 0V Supplementation: Standard similar as for IN2 to IN4 = 1.3V		0.2	0.3	V
	V _{OUT} 12	$I_{OUT} = 350$ mA,V _{CC} = 1.9V to 3.6V,V _{OUT} = Upper Tr and Under Tr IN1 = 1.3V,IN2 to IN4 = 0V Supplementation: Standard similar as for IN2 to IN4 = 1.3V		0.25	0.4	V
Output saturation voltage2 (parallel connection)	V _{OUT} 21	$I_{OUT} = 270$ mA,V _{CC} = 1.9V to 3.6V,V _{OUT} = Upper Tr and Under Tr OUT1-3,OUT2-4 short. IN1 and IN3 = 1.3V,IN2 and IN4 = 0V Supplementation: Standard similar as for IN2 and IN4 = 1.3V		0.12	0.2	V
	V _{OUT} 22	$I_{OUT} = 500$ mA,V _{CC} = 1.9V to 3.6V,V _{OUT} = Upper Tr and Under Tr OUT1-3,OUT2-4 short. IN1 and IN3 = 1.3V,IN2 and IN4 = 0V Supplementation: Standard similar as for IN2 and IN4 = 1.3V		0.2	0.35	V
Input current	IIN	V _{IN} = 1.9V		32	70	μA
Themal shutdown operation temperature	Ttsd			140		°C
Temperature hysteresis width	ΔT			20		°C
Spark killer Diode	·	· · · ·		· · · ·	I	
Reverse current	I _S (leak)	V _{CC} -OUT = 8V,V _{IN} = 0V			10	μA
Forword voltage	V _{SF}	I _{OUT} = 400mA,V _{IN} = 0V			1.7	V

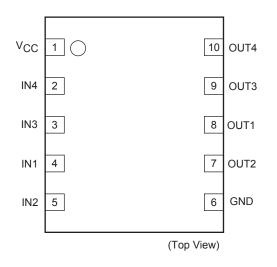
Package Dimensions

unit : mm (typ) 3086B





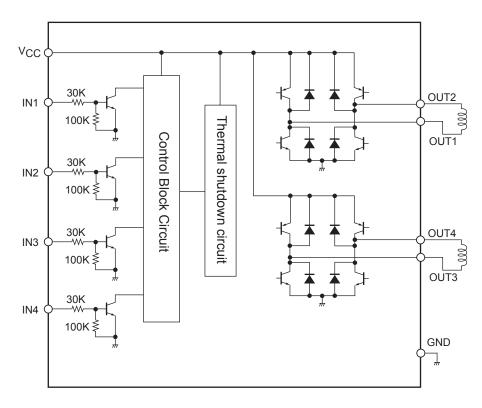
Pin Assignment



Truth Table

Input			Output			Mode		
IN1	IN2	IN3	IN4	OUT1	OUT2	OUT3	OUT4	Mode
Low	Low	Low	Low	Off	Off	Off	Off	Standby mode
High	Low	-		High	Low			Channel 1, forward
Low	High		-	Low	High	-	-	Channel 1, reverse
		High	Low		High	gh Low	Channel 2, forward	
-		Low	High			-	Low	High
High	High	-	-	The logic output for the first high-level input is produced.				
-	-	High	High					

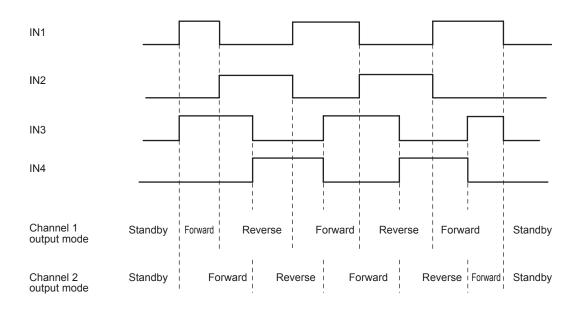
Block Diagram



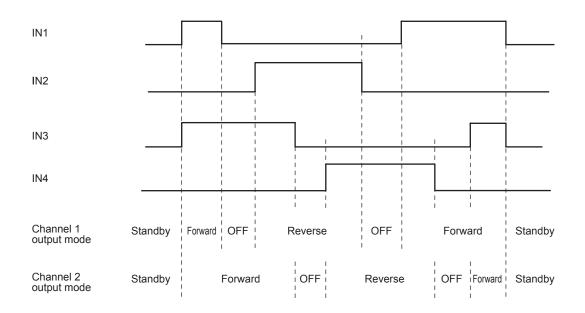
Timing Chart

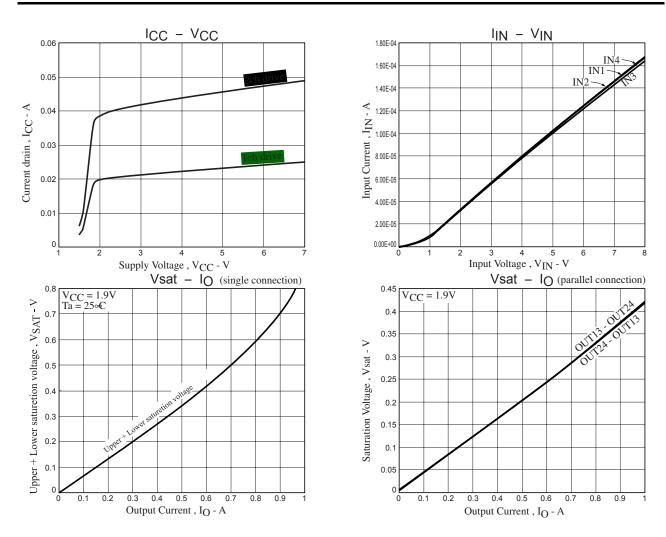
(1) Stepper motor timing chart

Timing chart for 2-phase drive



(2) Timing chart for 1-2 phase drive (Fastdecay mode)





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